

HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODES

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	2 x 10 A
V_{RRM}	200 V
T_j (max)	150 °C
V_F (max)	0.85 V
t_{rr} (max)	25 ns

PRELIMINARY DATASHEET

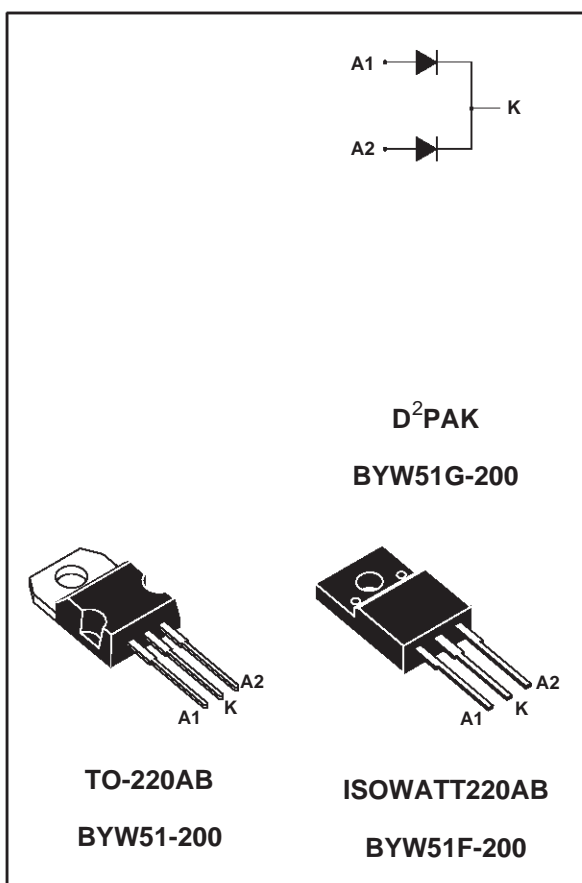
FEATURES AND BENEFITS

- SUITED FOR SMPS
- VERY LOW FORWARD LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- HIGH SURGE CURRENT CAPABILITY
- INSULATED PACKAGES (ISOWATT220AB / TO-220FP) :
Insulation voltage = 2500 V_(RMS)
Capacitance = 12 pF

DESCRIPTION

Dual center tap rectifier suited for Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in TO-220AB, ISOWATT220AB, TO-220FP or D²PAK, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter			Value	Unit	
V_{RRM}	Repetitive peak reverse voltage			200	V	
$I_{F(RMS)}$	RMS forward current			20	A	
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO-220AB/D ² PAK	$T_c=120^\circ\text{C}$	Per diode	10	A
				Per device	20	
		ISOWATT220AB	$T_c=95^\circ\text{C}$	Per diode	10	
				Per device	20	
		TO-220FP	$T_c=85^\circ\text{C}$	Per diode	10	
				Per device	20	
I_{FSM}	Surge non repetitive forward current		$t_p=10\text{ms}$ sinusoidal	100	A	
T_{stg}	Storage temperature range			- 65 to + 150	°C	
T_j	Maximum operating junction temperature			150	°C	

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.